# 74HC193; 74HCT193Presettable synchronous 4-bit binary up/down counterRev. 5 - 29 January 2016Product data

Product data sheet

## 1. General description

The 74HC193; 74HCT193 is a 4-bit synchronous binary up/down counter. Separate up/down clocks, CPU and CPD respectively, simplify operation. The outputs change state synchronously with the LOW-to-HIGH transition of either clock input. If the CPU clock is pulsed while CPD is held HIGH, the device will count up. If the CPD clock is pulsed while CPU is held HIGH, the device will count down. Only one clock input can be held HIGH at any time to guarantee predictable behavior. The device can be cleared at any time by the asynchronous master reset input (MR); it may also be loaded in parallel by activating the asynchronous parallel load input (PL). The terminal count up (TCU) and terminal count down (TCD) outputs are normally HIGH. When the circuit has reached the maximum count state of 15, the next HIGH-to-LOW transition of CPU will cause TCU to go LOW. TCU will stay LOW until CPU goes HIGH again, duplicating the count up clock. Likewise, the TCD output will go LOW when the circuit is in the zero state and the CPD goes LOW. The terminal count outputs can be used as the clock input signals to the next higher order circuit in a multistage counter, since they duplicate the clock waveforms. Multistage counters will not be fully synchronous, since there is a slight delay time difference added for each stage that is added. The counter may be preset by the asynchronous parallel load capability of the circuit. Information present on the parallel data inputs (D0 to D3) is loaded into the counter and appears on the outputs (Q0 to Q3) regardless of the conditions of the clock inputs when the parallel load (PL) input is LOW. A HIGH level on the master reset (MR) input will disable the parallel load gates, override both clock inputs and set all outputs (Q0 to Q3) LOW. If one of the clock inputs is LOW during and after a reset or load operation, the next LOW-to-HIGH transition of that clock will be interpreted as a legitimate signal and will be counted. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V<sub>CC</sub>.

#### 2. Features and benefits

- Input levels:
  - For 74HC193: CMOS level
  - For 74HCT193: TTL level
- Synchronous reversible 4-bit binary counting
- Asynchronous parallel load
- Asynchronous reset
- Expandable without external logic
- Complies with JEDEC standard no. 7A
- ESD protection:
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V.

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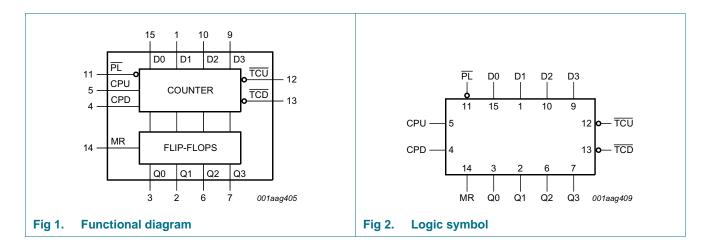
- Multiple package options
- Specified from –40 °C to +85 °C and –40 °C to +125 °C.

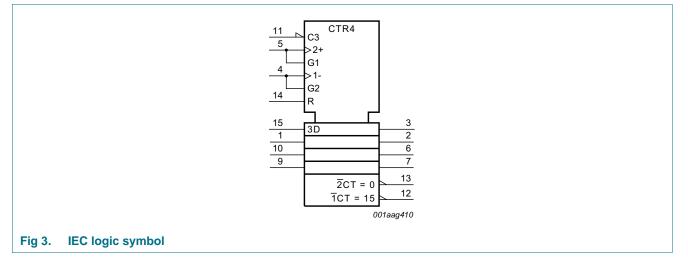
## 3. Ordering information

#### Table 1. Ordering information

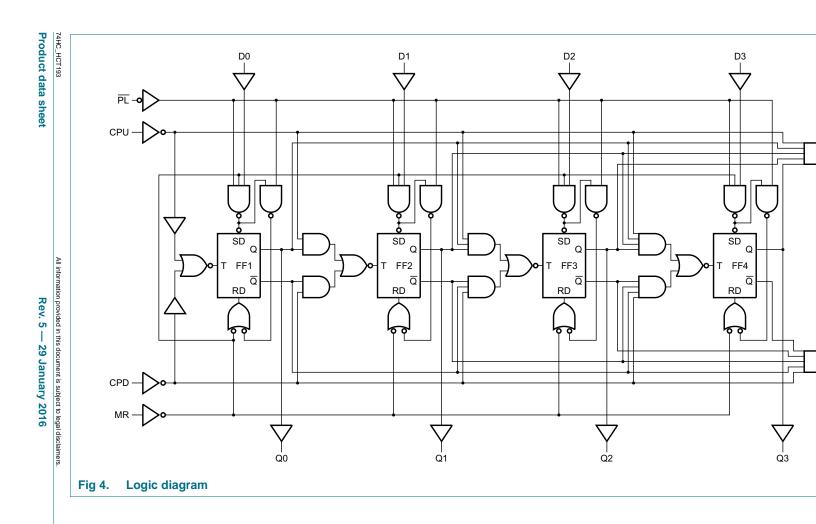
Type number	Package	Package									
	Temperature range	Name	Description	Version							
74HC193D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1							
74HCT193D			body width 3.9 mm								
74HC193DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads;	SOT338-1							
74HCT193DB			body width 5.3 mm								
74HC193PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1							
74HCT193PW			body width 4.4 mm								

## 4. Functional diagram





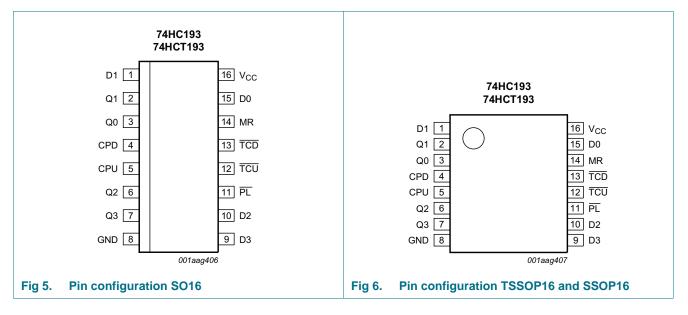
74HC\_HCT193



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## 5. Pinning information

#### 5.1 Pinning



#### 5.2 Pin description

#### Table 2. Pin description

Symbol	Pin	Description
D0	15	data input 0
D1	1	data input 1
D2	10	data input 2
D3	9	data input 3
Q0	3	flip-flop output 0
Q1	2	flip-flop output 1
Q2	6	flip-flop output 2
Q3	7	flip-flop output 3
CPD	4	count down clock input <sup>[1]</sup>
CPU	5	count up clock input <sup>[1]</sup>
GND	8	ground (0 V)
PL	11	asynchronous parallel load input (active LOW)
TCU	12	terminal count up (carry) output (active LOW)
TCD	13	terminal count down (borrow) output (active LOW)
MR	14	asynchronous master reset input (active HIGH)
V <sub>CC</sub>	16	supply voltage

[1] LOW-to-HIGH, edge triggered.

## 6. Functional description

#### Table 3. Function table<sup>[1]</sup>

Operating mode	Inputs						Outputs							
	MR	PL	CPU	CPD	D0	D1	D2	D3	Q0	Q1	Q2	Q3	TCU	TCD
Reset (clear)	Н	Х	Х	L	Х	Х	Х	Х	L	L	L	L	Н	L
	Н	Х	Х	Н	Х	Х	Х	Х	L	L	L	L	Н	Н
Parallel load	L	L	Х	L	L	L	L	L	L	L	L	L	Н	L
	L	L	Х	Н	L	L	L	L	L	L	L	L	Н	Н
	L	L	L	Х	Н	Н	Н	Н	Н	Н	Н	Н	L	Н
	L	L	Н	Х	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н
Count up	L	Н	$\uparrow$	Н	Х	Х	Х	Х	coun	t up			H[2]	Н
Count down	L	Н	Н	$\uparrow$	Х	Х	Х	Х	coun	ount down			Н	H <mark>[3]</mark>

[1] H = HIGH voltage level

L = LOW voltage level

X = don't care

 $\uparrow$  = LOW-to-HIGH clock transition.

[2]  $\overline{TCU} = CPU$  at terminal count up (HHHH)

[3]  $\overline{\text{TCD}} = \text{CPD}$  at terminal count down (LLLL).

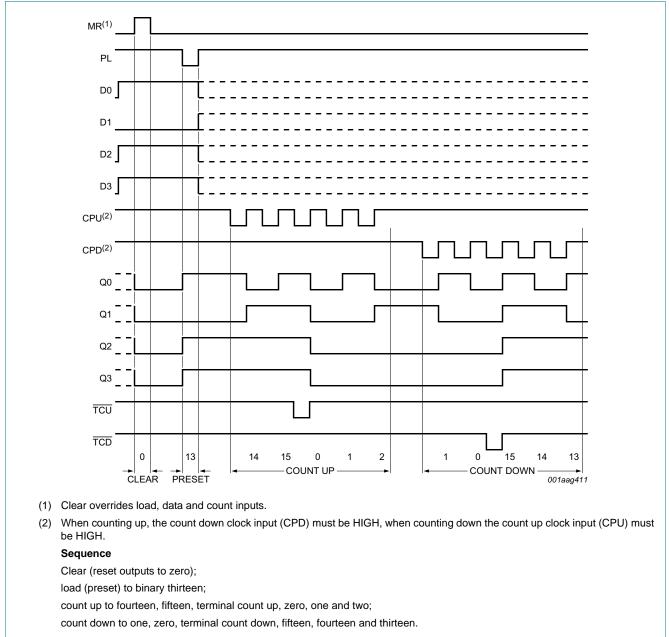


Fig 7. Typical clear, load and count sequence

## 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5$ V or $V_{I} > V_{CC} + 0.5$ V	<u>[1]</u>	-	±20	mA
Ι <sub>ΟΚ</sub>	output clamping current	$V_{O}$ < -0.5 V or $V_{O}$ > $V_{CC}$ + 0.5 V	<u>[1]</u>	-	±20	mA
lo	output current	$V_{O} = -0.5 \text{ V}$ to $V_{CC} + 0.5 \text{ V}$		-	±25	mA
I <sub>CC</sub>	supply current			-	50	mA
I <sub>GND</sub>	ground current			-	-50	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	SO16 package	[2]	-	500	mW
		SSOP16 package	[2]	-	500	mW
		TSSOP16 package	[2]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SO16 packages: above 70 °C the value of P<sub>tot</sub> derates linearly at 8 mW/K.
 For SSOP16 and TSSOP16 packages: above 60 °C the value of P<sub>tot</sub> derates linearly at 5.5 mW/K.

## 8. Recommended operating conditions

#### Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
74HC19	3					
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	V
VI	input voltage		0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	-	625	ns/V
		V <sub>CC</sub> = 4.5 V	-	1.67	139	ns/V
		V <sub>CC</sub> = 6.0 V	-	-	83	ns/V
74HCT1	93					
V <sub>CC</sub>	supply voltage		4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 4.5 V	-	1.67	139	ns/V

## 9. Static characteristics

#### Table 6. Static characteristics type 74HC193

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 25	°C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	V
		V <sub>CC</sub> = 4.5 V	3.15	2.4	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	V
		V <sub>CC</sub> = 4.5 V	-	2.1	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$	-	-	-	
		$I_{O} = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	2.0	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	4.5	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_0 = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	0	0.1	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	V
		$I_0 = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	V
li	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±0.1	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	8.0	μA
C <sub>i</sub>	input capacitance		-	3.5	-	pF
T <sub>amb</sub> = -40	) °C to +85 °C	I				
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC} = 2.0 V$	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	1.9	-	-	V
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	-	-	V
		$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 6.0 \ \text{V}$	5.9	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	-	-	V
		$I_0 = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.34	-	-	V

#### Table 6. Static characteristics type 74HC193 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_0 = 20 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	-	-	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.33	V
		$I_0 = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.33	V
lı	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±1.0	μA
I <sub>CC</sub>	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	80	μA
$T_{amb} = -40$	) °C to +125 °C		I	1		
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		$V_{CC} = 4.5 V$	3.15	-	-	V
		$V_{CC} = 6.0 V$	4.2	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		$V_{CC} = 4.5 V$	-	-	1.35	V
		$V_{CC} = 6.0 V$	-	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_0 = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	-	-	V
		$I_0 = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	-	-	V
		$I_0 = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.2	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_0 = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	-	0.1	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.4	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.4	V V V V V V V V V V V V V V V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	±1.0	μA
I <sub>CC</sub>	supply current	$V_{I} = V_{CC} \text{ or GND; } I_{O} = 0 \text{ A;}$ $V_{CC} = 6.0 \text{ V}$	-	-	160	μA

#### Table 7. Static characteristics type 74HCT193

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 25 °	C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
		I <sub>O</sub> = -20 μA	4.4	4.5	-	V
		$I_{O} = -4.0 \text{ mA}$	3.98	4.32	-	V

#### Table 7. Static characteristics type 74HCT193 ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
		I <sub>O</sub> = 20 μA	-	0	0.1	V
		I <sub>O</sub> = 4.0 mA	-	0.15	0.26	V
1	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.1	μA
I <sub>CC</sub>	supply current	$V_{I} = V_{CC} \text{ or GND}; I_{O} = 0 \text{ A};$ $V_{CC} = 5.5 \text{ V}$	-	-	8.0	μA
Δl <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1$ V and other inputs at $V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 4.5$ V to 5.5 V				
		pin Dn	-	35	126	μA
		pins CPU, CPD	-	140	504	μA
		pin PL	-	65	234	μA
		pin MR	-	105	378	μA
C <sub>i</sub>	input capacitance		-	3.5	-	pF
T <sub>amb</sub> = -40	0 °C to +85 °C				•	
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$	-	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
		I <sub>O</sub> = -20 μA	4.4	-	-	V
		$I_{O} = -4.0 \text{ mA}$	3.84	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
		I <sub>O</sub> = 20 μA	-	-	0.1	V
		l <sub>O</sub> = 4.0 mA	-	-	0.33	V
l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±1.0	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	80	μA
Δl <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$ and other inputs at $V_{CC}$ or GND; $I_O = 0 \text{ A}$ ; $V_{CC} = 4.5 \text{ V}$ to 5.5 V				
		pin Dn	-	-	157.5	μA
		pins CPU, CPD	-	-	630	μA
		pin PL	-	-	292.5	μA
		pin MR	-	-	472.5	μA
T <sub>amb</sub> = -40	0 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	-	-	0.8	V
V <sub>он</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
		I <sub>O</sub> = -20 μA	4.4	-	-	V
		$I_{O} = -4.0 \text{ mA}$	3.7	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
		I <sub>O</sub> = 20 μA	-	-	0.1	V
		$I_0 = 4.0 \text{ mA}$	-	-	0.4	V

#### Table 7. Static characteristics type 74HCT193 ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
կ	input leakage current	$V_1 = V_{CC}$ or GND; $V_{CC} = 5.5$ V	-	-	±1.0	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	160	μΑ
ΔI <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1$ V and other inputs at $V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 4.5$ V to 5.5 V				
		pin Dn	-	-	171.5	μA
		pins CPU, CPD	-	-	686	μA
		pin PL	-	-	318.5	μA
		pin MR	-	-	514.5	μA

## **10.** Dynamic characteristics

#### Table 8. Dynamic characteristics type 74HC193

Symbol	Parameter	Conditions		25 °C		–40 °C to	+85 °C	–40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>pd</sub>	propagation delay	CPU, CPD to Qn; [1] see Figure 8	-							
		V <sub>CC</sub> = 2.0 V	-	63	215	-	270	-	325	ns
		V <sub>CC</sub> = 4.5 V	-	23	43	-	54	-	65	ns
		V <sub>CC</sub> = 6.0 V	-	18	37	-	46	-	55	ns
		CPU to TCU; see Figure 9								
		V <sub>CC</sub> = 2.0 V	-	39	125	-	155	-	190	ns
		V <sub>CC</sub> = 4.5 V	-	14	25	-	31	-	38	ns
		V <sub>CC</sub> = 6.0 V	-	11	21	-	26	-	32	ns
		CPD to TCD; see Figure 9								
		V <sub>CC</sub> = 2.0 V	-	39	125	-	155	-	190	ns
		V <sub>CC</sub> = 4.5 V	-	14	25	-	31	-	38	ns
		V <sub>CC</sub> = 6.0 V	-	11	21	-	26	-	32	ns
		PL to Qn; see Figure 10								
		V <sub>CC</sub> = 2.0 V	-	69	220	-	275	-	330	ns
		V <sub>CC</sub> = 4.5 V	-	25	44	-	55	-	66	ns
		V <sub>CC</sub> = 6.0 V	-	20	37	-	47	-	56	ns
		MR to Qn; see Figure 11								
		V <sub>CC</sub> = 2.0 V	-	58	200	-	250	-	300	ns
		V <sub>CC</sub> = 4.5 V	-	21	40	-	50	-	60	ns
		V <sub>CC</sub> = 6.0 V	-	17	34		43	-	51	ns
		Dn to Qn; see Figure 10								
		V <sub>CC</sub> = 2.0 V	-	69	210	-	265	-	315	ns
		V <sub>CC</sub> = 4.5 V	-	25	42	-	53	-	63	ns
		V <sub>CC</sub> = 6.0 V	-	20	36	-	45	-	54	ns
		PL to TCU, PL to TCD; see Figure 13								
		V <sub>CC</sub> = 2.0 V	-	80	290	-	365	-	435	ns
		V <sub>CC</sub> = 4.5 V	-	29	58	-	73	-	87	ns
		V <sub>CC</sub> = 6.0 V	-	23	49	-	62	-	74	ns
		MR to TCU, MR to TCD; see Figure 13								
		V <sub>CC</sub> = 2.0 V	-	74	285	-	355	-	430	ns
		V <sub>CC</sub> = 4.5 V	-	27	57	-	71	-	86	ns
		V <sub>CC</sub> = 6.0 V	-	22	48	-	60	-	73	ns

Symbol	Parameter	Conditions		25 °C		–40 °C to	40 °C to +85 °C –40 °C to +125 °C			
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>pd</sub>	propagation delay	Dn to TCU, Dn to TCD; see Figure 13								
		V <sub>CC</sub> = 2.0 V	-	80	290	-	365	-	435	ns
		V <sub>CC</sub> = 4.5 V	-	29	58	-	73	-	87	ns
		V <sub>CC</sub> = 6.0 V	-	23	49	-	62	-	74	ns
t <sub>THL</sub>	HIGH to LOW	see Figure 11								
	output transition	V <sub>CC</sub> = 2.0 V	-	19	75	-	95	-	110	ns
	time	V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
		V <sub>CC</sub> = 6.0 V	-	6	13	-	16	-	19	ns
TLH	LOW to HIGH	see Figure 11								
	output	V <sub>CC</sub> = 2.0 V	-	19	75	-	95	-	110	ns
	transition time	$V_{CC} = 4.5 V$	-	7	15	-	19	-	22	ns
		V <sub>CC</sub> = 6.0 V	-	6	13	-	16	-	19	ns
tw	pulse width	CPU, CPD (HIGH or LOW); see <u>Figure 8</u>								
		V <sub>CC</sub> = 2.0 V	100	22	-	125	-	150	-	ns
		V <sub>CC</sub> = 4.5 V	20	8	-	25	-	30	-	ns
		V <sub>CC</sub> = 6.0 V	17	6	-	21	-	26	-	ns
		MR (HIGH); see Figure 11								
		$V_{CC} = 2.0 V$	100	25	-	125	-	150	-	ns
		$V_{CC} = 4.5 V$	20	9	-	25	-	30	-	ns
		V <sub>CC</sub> = 6.0 V	17	7	-	21	-	26	-	ns
		PL (LOW); see Figure 10								
		V <sub>CC</sub> = 2.0 V	100	19	-	125	-	150	-	ns
		$V_{CC} = 4.5 V$	20	7	-	25	-	30	-	ns
		V <sub>CC</sub> = 6.0 V	17	6	-	21	-	26	-	ns
t <sub>rec</sub>	recovery time	PL to CPU, CPD; see Figure 10								
		V <sub>CC</sub> = 2.0 V	50	8	-	65	-	75	-	ns
		V <sub>CC</sub> = 4.5 V	10	3	-	13	-	15	-	ns
		V <sub>CC</sub> = 6.0 V	9	2	-	11	-	13	-	ns
		MR to CPU, CPD; see <u>Figure 11</u>								
		V <sub>CC</sub> = 2.0 V	50	0	-	65	-	75	-	ns
		V <sub>CC</sub> = 4.5 V	10	0	-	13	-	15	-	ns
		V <sub>CC</sub> = 6.0 V	9	0	-	11	-	13	-	ns
su	set-up time	Dn to $\overline{PL}$ ; see <u>Figure 12</u> ; note: CPU = CPD = HIGH								
		V <sub>CC</sub> = 2.0 V	80	22	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	8	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	6	-	17	-	20	-	ns

#### Table 8. Dynamic characteristics type 74HC193 ...continued

Symbol	Parameter	Conditions		25 °C		–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>h</sub>	hold time	Dn to PL; see Figure 12								
		V <sub>CC</sub> = 2.0 V	0	-14	-	0	-	0	-	ns
		V <sub>CC</sub> = 4.5 V	0	-5	-	0	-	0	-	ns
		V <sub>CC</sub> = 6.0 V	0	-4	-	0		0	-	ns
		CPU to CPD, CPD to CPU; see Figure 14								
		V <sub>CC</sub> = 2.0 V	80	22	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	8	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	8	6	-	17	-	20	-	ns
f <sub>max</sub>	maximum	CPU, CPD; see Figure 8								
	frequency	V <sub>CC</sub> = 2.0 V	4.0	13.5	-	3.2	-	2.6	-	MHz
		V <sub>CC</sub> = 4.5 V	20	41	-	16	-	13	-	MHz
		V <sub>CC</sub> = 6.0 V	24	49	-	19	-	15	-	MHz
C <sub>PD</sub>	power dissipation capacitance	$V_{I} = GND \text{ to } V_{CC}; \qquad [2]$ $V_{CC} = 5 \text{ V}; f_{I} = 1 \text{ MHz}$	-	24	-	-	-	-	-	pF

#### Table 8. Dynamic characteristics type 74HC193 ...continued

[1]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

[2]  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

 $f_o = output frequency in MHz;$ 

 $C_L$  = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

Symbol	Parameter	Conditions	25 °C		–40 °C to +85 °C		–40 °C to +125 °C		Unit	
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>pd</sub>	propagation	CPU, CPD to Qn; [1]								
	delay	see Figure 8								
		$V_{CC} = 4.5 V$	-	23	43	-	54	-	65	ns
		CPU to TCU; see Figure 9								
		$V_{CC} = 4.5 V$	-	15	27	-	34	-	41	ns
		CPD to TCD; see Figure 9								
		$V_{CC} = 4.5 V$	-	15	27	-	34	-	41	ns
		PL to Qn; see Figure 10								
		V <sub>CC</sub> = 4.5 V	-	26	46	-	58	-	69	ns
		MR to Qn; see Figure 11								
		V <sub>CC</sub> = 4.5 V	-	22	40	-	50	-	60	ns
		Dn to Qn; see Figure 10								
		V <sub>CC</sub> = 4.5 V	-	27	46	-	58	-	69	ns
		PL to TCU, PL to TCD; see Figure 13								
		$V_{CC} = 4.5 V$	-	31	55	-	69	-	83	ns
		MR to TCU, MR to TCD; see Figure 13								
		$V_{\rm CC} = 4.5 \text{ V}$	-	29	55	-	69	-	83	ns
		Dn to TCU, Dn to TCD; see Figure 13								
		V <sub>CC</sub> = 4.5 V	-	32	58	-	73	-	87	ns
THL	HIGH to LOW	see Figure 11								
	output transition time	V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
TLH	LOW to HIGH	see Figure 11								
	output transition time	V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
Ŵ	pulse width	CPU, CPD (HIGH or LOW); see <u>Figure 8</u>								
		V <sub>CC</sub> = 4.5 V	25	11	-	31	-	38	-	ns
		MR (HIGH); see Figure 11								
		V <sub>CC</sub> = 4.5 V	20	7	-	25	-	30	-	ns
		PL (LOW); see Figure 10								
		V <sub>CC</sub> = 4.5 V	20	8	-	25	-	30	-	ns
rec	recovery time	PL to CPU, CPD;								
		see Figure 10								
		V <sub>CC</sub> = 4.5 V	10	2	-	13	-	15	-	ns
		MR to CPU, CPD; see Figure 11								
		$V_{CC} = 4.5 V$	10	0	_	13	-	15		ns

#### Table 9. Dynamic characteristics type 74HCT193

Symbol	Parameter	Conditions	25 °C		–40 °C to +85 °C		–40 °C to +125 °C		Unit	
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>su</sub>	set-up time	Dn to PL; see Figure 12; note: CPU = CPD = HIGH								
		V <sub>CC</sub> = 4.5 V	16	8	-	20	-	24	-	ns
t <sub>h</sub> hold	hold time	Dn to PL; see Figure 12								
		V <sub>CC</sub> = 4.5 V	0	-6	-	0	-	0	-	ns
		CPU to CPD, CPD to CPU; see Figure 14								
		V <sub>CC</sub> = 4.5 V	16	7	-	20	-	24	-	ns
f <sub>max</sub>	maximum	CPU, CPD; see Figure 8								
	frequency	V <sub>CC</sub> = 4.5 V	20	43	-	16	-	13	-	MHz
C <sub>PD</sub>	power dissipation capacitance	$V_{I} = GND \text{ to } V_{CC} - 1.5 \text{ V}; \qquad [2] \\ V_{CC} = 5 \text{ V};  f_{i} = 1 \text{ MHz}$	-	26	-	-	-	-	-	pF

#### Table 9. Dynamic characteristics type 74HCT193 ...continued

 $\label{eq:tpd} [1] \quad t_{pd} \mbox{ is the same as } t_{PHL} \mbox{ and } t_{PLH}.$ 

[2]  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W):

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \sum (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$  $f_{i} = \text{input frequency in MHz;}$ 

 $f_0 = output frequency in MHz;$ 

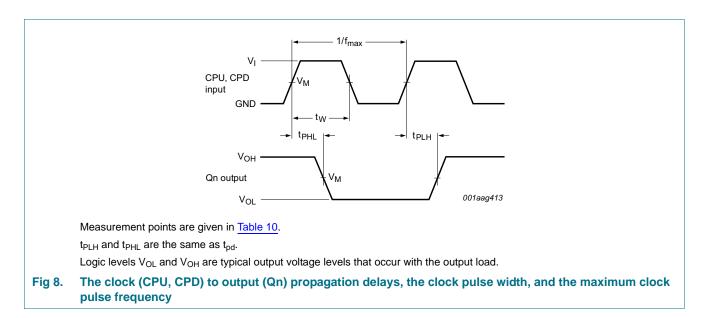
 $C_L$  = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$  = sum of outputs.

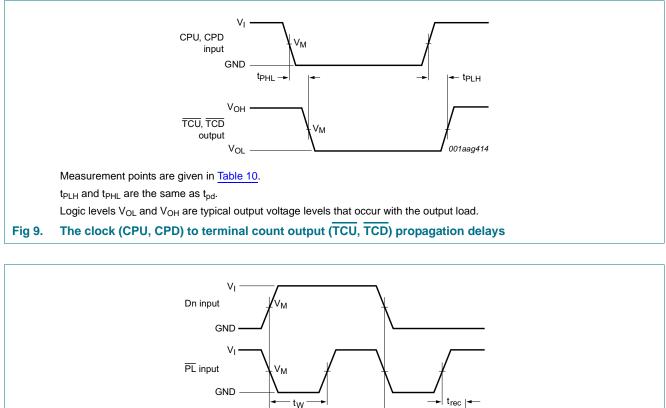
#### 11. Waveforms

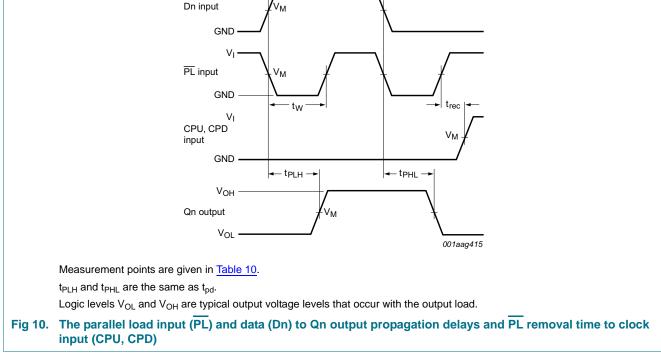


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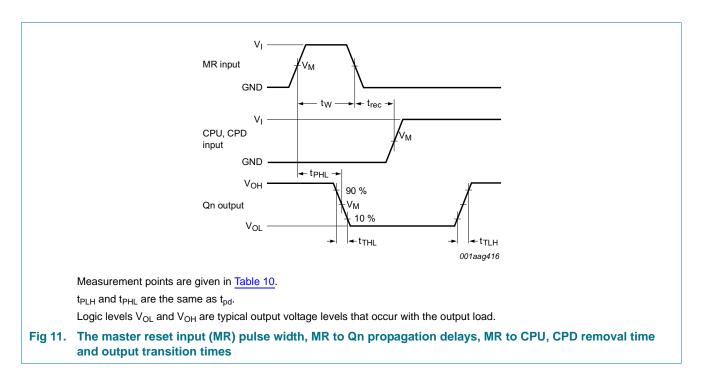
## 74HC193; 74HCT193

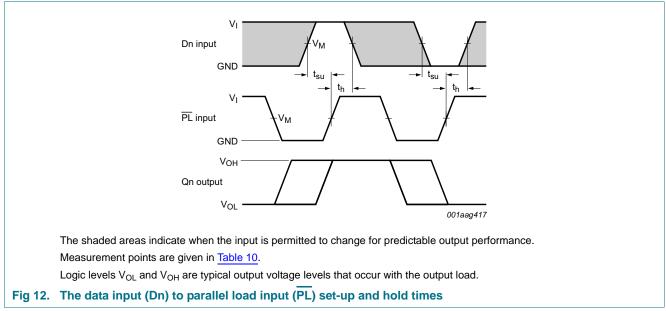
#### Presettable synchronous 4-bit binary up/down counter





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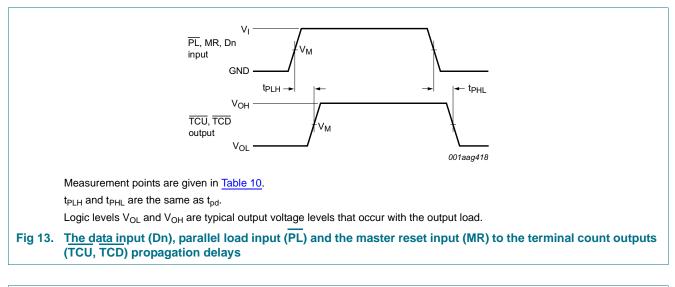


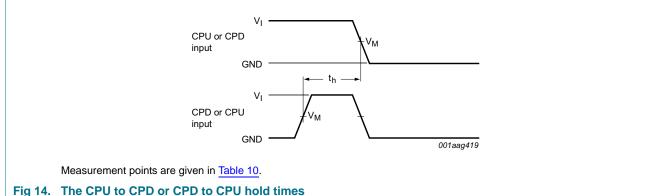


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## 74HC193; 74HCT193

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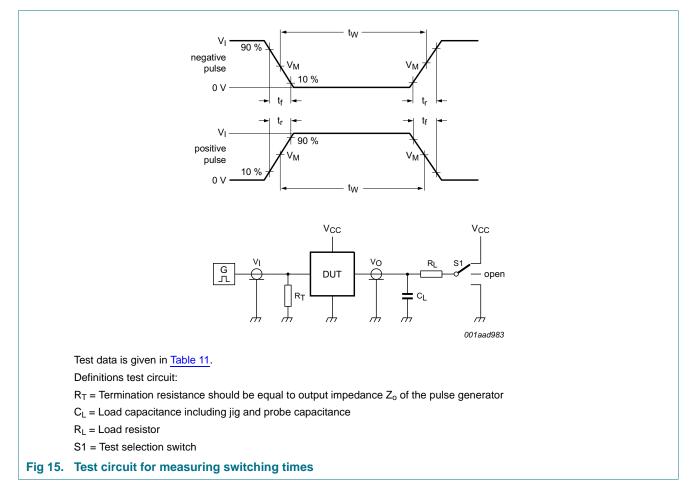




#### Table 10. Measurement points

Туре	Input	Output	
	V <sub>M</sub>	Vi	V <sub>M</sub>
74HC193	$0.5  imes V_{CC}$	GND to V <sub>CC</sub>	$0.5 \times V_{CC}$
74HCT193	1.3 V	GND to 3 V	1.3 V

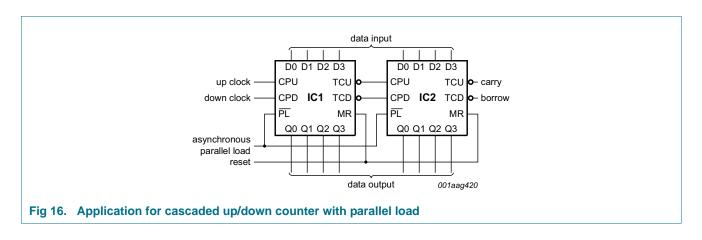
#### Presettable synchronous 4-bit binary up/down counter



#### Table 11. Test data

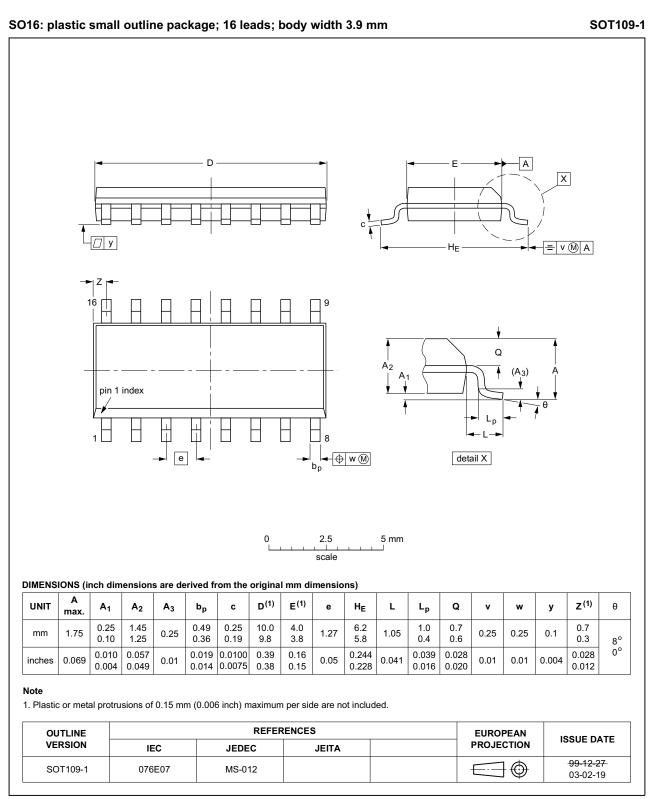
Туре	Input		Load	S1 position	
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PHL</sub> , t <sub>PLH</sub>
74HC193	V <sub>CC</sub>	6 ns	15 pF, 50 pF	1 kΩ	open
74HCT193	3 V	6 ns	15 pF, 50 pF	1 kΩ	open

## **12. Application information**



#### Presettable synchronous 4-bit binary up/down counter

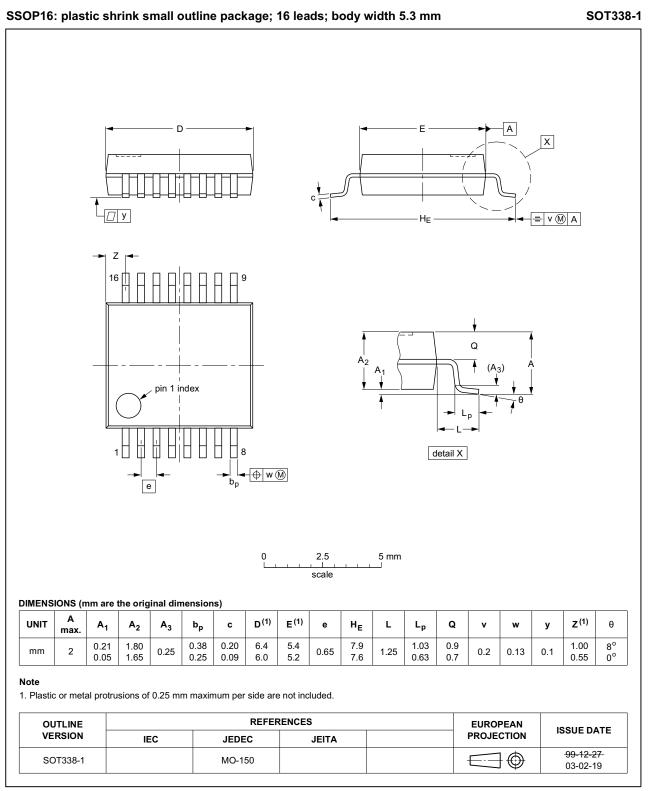
#### 13. Package outline



#### Fig 17. Package outline SOT109-1 (SO16)

74HC\_HCT193

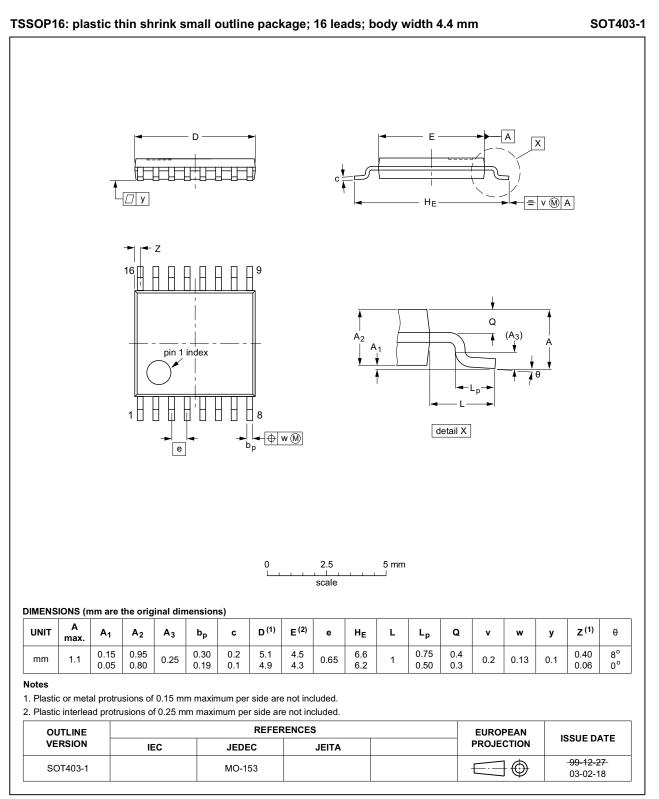
#### Presettable synchronous 4-bit binary up/down counter



#### Fig 18. Package outline SOT338-1 (SSOP16)

74HC\_HCT193

#### Presettable synchronous 4-bit binary up/down counter



#### Fig 19. Package outline SOT403-1 (TSSOP16)

74HC\_HCT193

## 14. Abbreviations

Table 12. Abbreviations					
Acronym	Description				
CMOS	Complementary Metal-Oxide Semiconductor				
DUT	Device Under Test				
ESD	ElectroStatic Discharge				
НВМ	Human Body Model				
MM	Machine Model				
TTL	Transistor-Transistor Logic				

## 15. Revision history

#### Table 13.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT193 v.5	20160129	Product data sheet	-	74HC_HCT193 v.4		
Modifications:	Type numbers 74HC193N and 74HCT193N (SOT38-4) removed.					
74HC_HCT193 v.4	20130624	Product data sheet	-	74HC_HCT193 v.3		
Modifications:	General description updated.					
74HC_HCT193 v.3	20070523	Product data sheet	-	74HC_HCT193_CNV v.2		
Modifications:	Modifications:              • The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.					
	<ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>					
	Family specification included					
74HC_HCT193_CNV v.2	19970828	Product specification	-	-		

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#### 16.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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